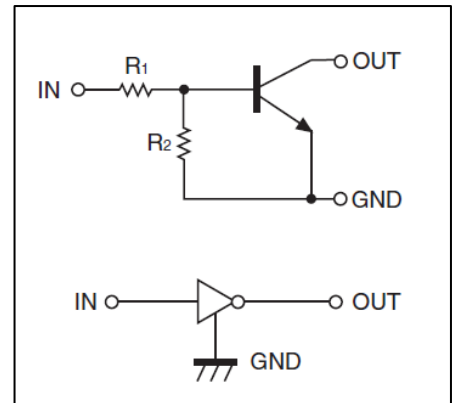


NPN Silicon Epitaxial Planar Digital Transistor

FEATURES

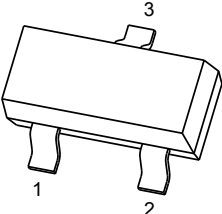
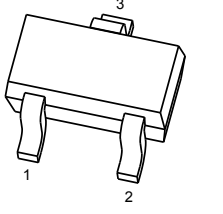
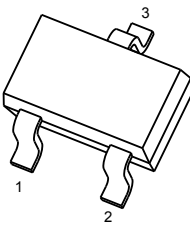
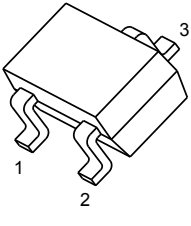
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input.They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device designs easy

Equivalent Circuit



MARKING: 24

PIN CONNENCTIONS and MARKING

<p>DTC114ECA</p>  <p>SOT-23</p> <p>1. IN 2. GND 3. OUT</p>	<p>DTC114EE</p>  <p>SOT-523</p> <p>1. IN 2. GND 3. OUT</p>
<p>DTC114EUA</p>  <p>SOT-323</p> <p>1. IN 2. GND 3. OUT</p>	<p>DTC114EKA</p>  <p>SOT-23-3L</p> <p>1. IN 2. GND 3. OUT</p>

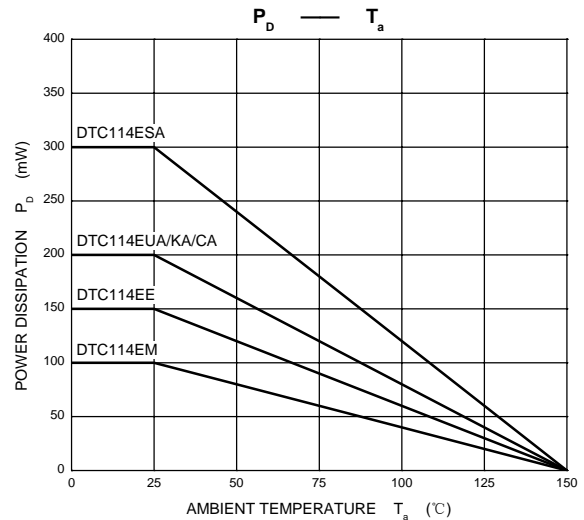
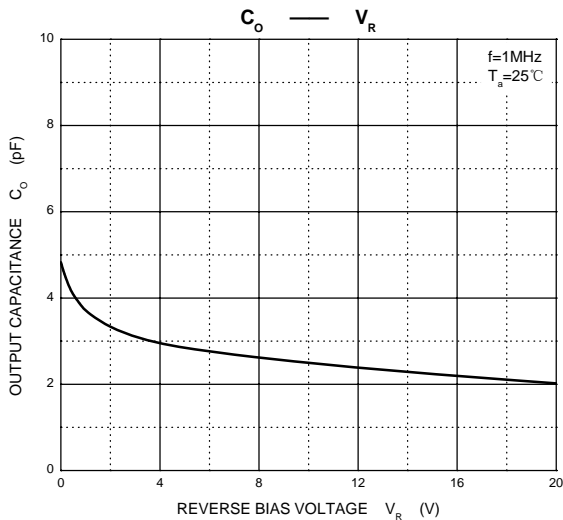
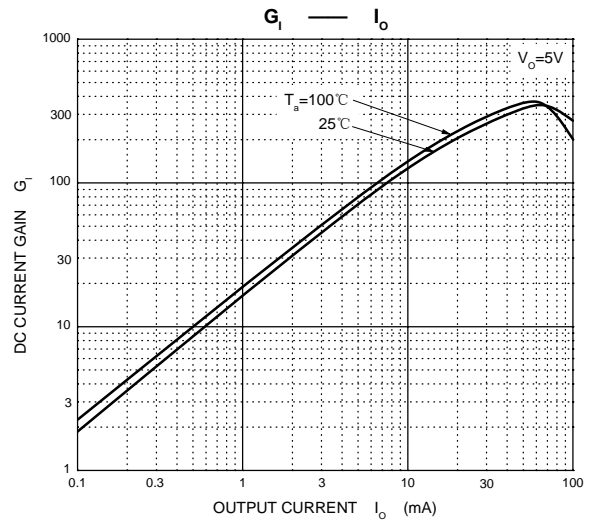
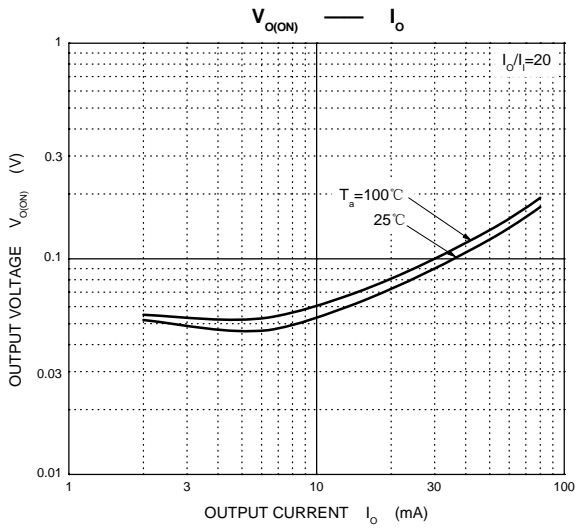
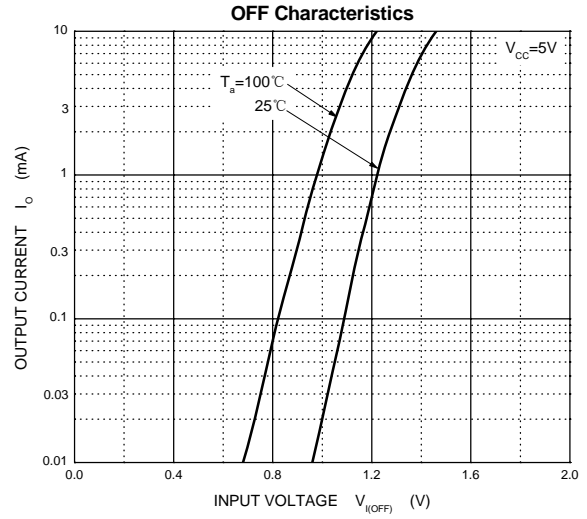
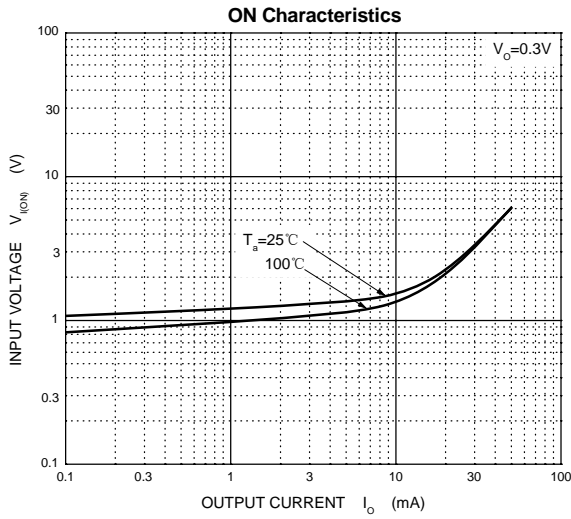
MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTC114E□)					Unit
			E	UA	CA	KA	
V _{CC}	Supply Voltage	50					V
V _{IN}	Input Voltage	-10~+40					V
I _O	Output Current	50					mA
I _{CM}	Peak Collector Current	100					mA
P _D	Power Dissipation		150	200	200	200	mW
T _J	Junction Temperature	150					°C
T _{stg}	Storage Temperature	-55~+150					°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

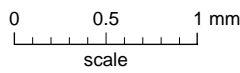
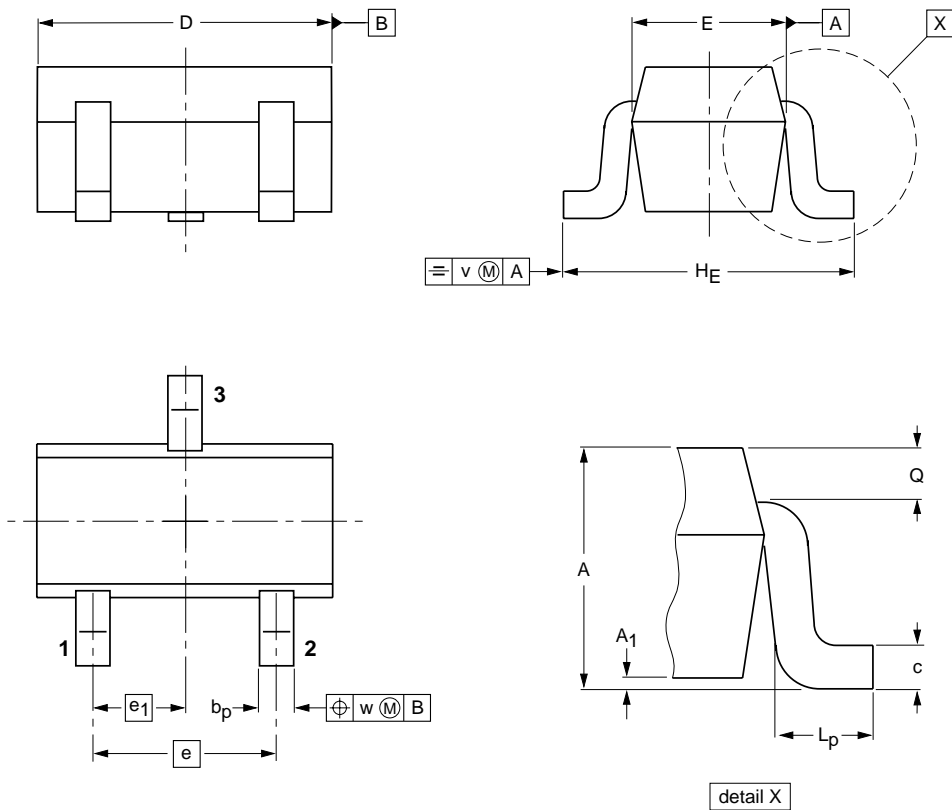
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =5V, I _O =100μA	0.5			V
	V _{I(on)}	V _O =0.3V, I _O =10mA			3	V
Output voltage	V _{O(on)}	I _O /I _I =10mA/0.5mA			0.3	V
Input current	I _I	V _I =5V			0.88	mA
Output current	I _{O(off)}	V _{CC} =50V, V _I =0			0.5	μA
DC current gain	G _I	V _O =5V, I _O =5mA	30			
Input resistance	R ₁		7	10	13	kΩ
Resistance ratio	R ₂ /R ₁		0.8	1	1.2	
Transition frequency	f _T	V _O =10V, I _O =5mA, f=100MHz		250		MHz

TYPICAL CHARACTERISTICS



PACKAGE OUTLINE

SOT-523



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

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[DTC115TKAT146](#) [DTC124TETL](#) [DTC144VUAT106](#) [MUN5241T1G](#) [BCR158WH6327XTSA1](#) [NSBA114TDP6T5G](#) [NSBA123EF3T5G](#)
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[DTA113EM3T5G](#) [DTC113EM3T5G](#) [NSVMUN5135DW1T1G](#) [NSVMUN2237T1G](#) [NSVDTC143ZM3T5G](#) [SMUN5335DW1T2G](#)
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